

DATA SHEET

SURFACE-MOUNT CERAMIC MULTILAYER CAPACITORS C-Array: Class 1, NPO 50 V

size 0612 (4 × 0603)



Phicomp

Product specification

C Array: Class 1, NP0 50 V size 0612 (4 × 0603)

FEATURES

- 4 × 0603 capacitors (of the same capacitance value) per array
- Less than 50% board space of an equivalent discrete component
- High volumetric efficiency
- Dense dielectric layers
- Supplied in tape on reel
- Increased throughput by time saved in mounting
- Cost savings on manufacturing time.

APPLICATIONS

- Professional electronics
- High density consumer electronics
- Automotive.

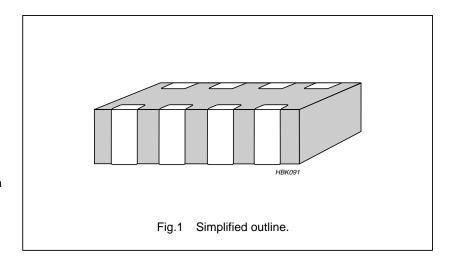
DESCRIPTION

Each capacitor element consists of a rectangular block of ceramic dielectric in which a number of interleaved precious metal electrodes are contained. This structure gives rise to a high capacitance per unit volume.

The inner electrodes are connected to the two terminations, silver dipped with a barrier layer of plated nickel and finally covered with a layer of plated tin (NiSn). An outline of the structure is shown in Fig.1.

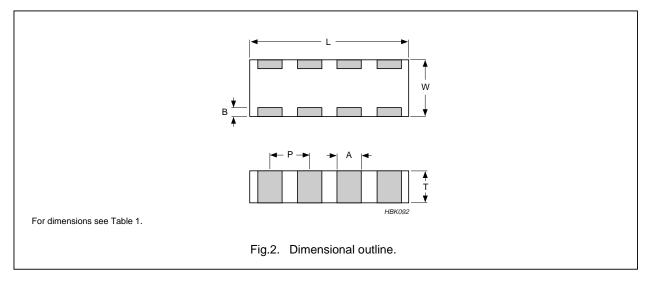
QUICK REFERENCE DATA

DESCRIPTION	VALUE
Rated voltage U _R (DC)	50 V (IEC)
Capacitance range (E12 series)	10 pF to 1 nF
Tolerance on capacitance	±5%, ±10%
Test voltage (DC) for 1 minute	$2.5 \times U_R$
Sectional specifications	IEC 60384-10, second edition 1989-04; also based on CECC 32 100
Detailed specification	based on CECC 32 101-801
Climatic category (IEC 60068)	55/125/56



C Array: Class 1, NP0 50 V size 0612 (4 × 0603)

MECHANICAL DATA



Physical dimensions

 Table 1
 Capacitor dimensions; see Fig.2

CASE SIZE	L	W	Т	Α	В	Р	
Dimensions in	Dimensions in millimetres						
0612 (4 × 0603)	3.2 ±0.15	1.60 ±0.15	0.80 ±0.10	0.40 ±0.10	0.30 ±0.20	0.80 ±0.10	
Dimensions in	Dimensions in inches						
0612 (4 × 0603)	0.126 ±0.006	0.063 ±0.006	0.032 ±0.004	0.016 ±0.004	0.012 ±0.008	0.031 ±0.004	

C Array: Class 1, NP0 50 V size 0612 (4 × 0603)

DIMENSIONS OF SOLDER LANDS

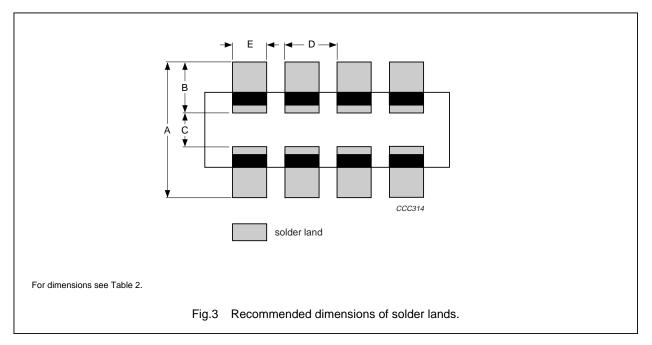


Table 2Solder land dimensions; see Fig.3

CASE SIZE	FOOTPRINT DIMENSIONS (mm)				
	Α	В	С	D	E
0612 (4 × 0603)	2.54 ±0.15	0.89 ±0.10	0.76 ±0.10	0.80 ±0.10	0.45 ±0.10

C Array: Class 1, NP0 50 V size 0612 (4 × 0603)

C	LAST TWO	50 V
C (pF)	DIGITS OF 12NC	0612 (4 × 0603)
10	23	
12	24	
15	25	
18	26	
22	27	
27	28	
33	29	
39	31	
47	32	
56	33	
68	34	
82	35	
100	36	0.8 ±0.1
120	37	
150	38	
180	39	
220	41	
270	42	
330	43	
390	44	
470	45	
560	46	
680	47	
820	48	
1 000	49	

SELECTION CHART FOR 50 V

Note

1. Values in shaded cells indicate thickness class.

Thickness classification and packing quantities

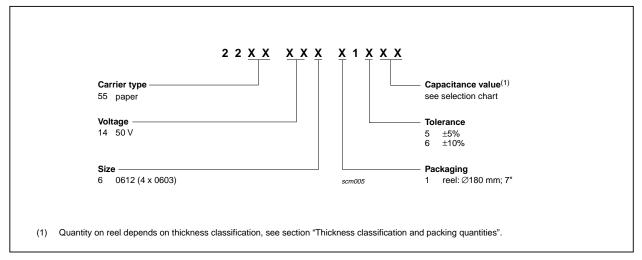
THICKNESS	8 mm TAPE WIDTH QUANTITY PER REEL	
CLASSIFICATION	Ø180 mm; 7"	
(mm)	PAPER	
0.8 ±0.1	4 000	

C Array: Class 1, NP0 50 V size 0612 (4 × 0603)

ORDERING INFORMATION

Components may be ordered by using either a Phycomp's unique 12NC or simple 15-digit clear text code.

Ordering code 12NC (preferred)



Clear text code

Example: 0612CG102J9B200

Size Code	Temp. Char.	Capacitance	Tol.	Vol.	Termination	Packing	Marking	Series
0612 (4 × 0603)	CG = NP0	102 = 1000 pF; the third digit signifies the multiplying factor: $0 = \times 1$ $1 = \times 10$ $2 = \times 100$	J = ±5% K = ±10%	9 = 50 V	B = NiSn	2 = 180 mm; 7" paper	0 = no marking	0 = conv. ceramic

C Array: Class 1, NP0 50 V size 0612 (4 × 0603)

ELECTRICAL CHARACTERISTICS

Class 1 capacitors; NP0 dielectric; NiSn terminations

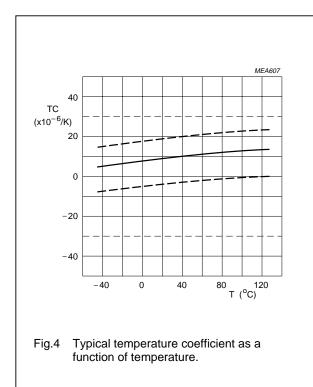
Unless otherwise stated all electrical values apply at an ambient temperature of 20 \pm 1 °C, an atmospheric pressure of 86 to 106 kPa, and a relative humidity of 63 to 67%.

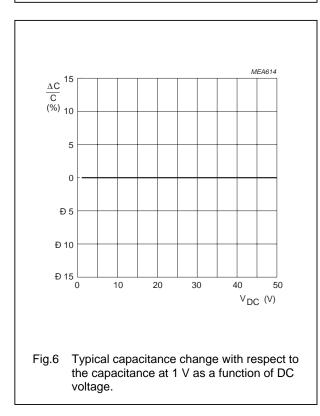
DESCRIPTION	VALUE
Capacitance range (E12 series); note 1	10 pF to 1 nF
Tolerance on capacitance after 1000 hours	±5%; 10%
Test voltage (DC) for 1 minute	$2.5 \times U_R$
Tan δ ; note 1	≤ 0.1%
Insulation resistance after 1 minute at U _R (DC):	R _{ins} ≥100 GΩ
Temperature coefficient	$(0 \pm 30) \times 10^{-6}$ /K

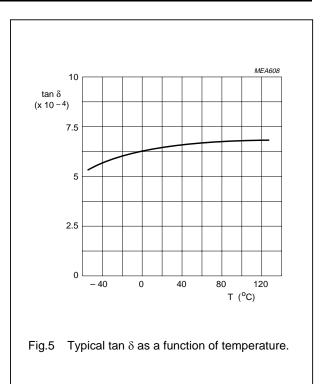
Note

1. Measured at 1 V, 1 MHz for C \leq 1000 pF and at 1 V, 1 kHz for C > 1000 pF, using a four-gauge method.

C Array: Class 1, NP0 50 V size 0612 (4 × 0603)







C Array: Class 1, NP0 50 V size 0612 (4 × 0603)

TESTS AND REQUIREMENTS

IEC 60384-10/ CECC 32 100 CLAUSE	IEC 60068-2 TEST METHOD	TEST PROCEDURE		REQUIREMENTS
4.4		mounting	the capacitors may be mounted on printed-circuit boards or ceramic substrates by applying wave soldering, reflow soldering (including vapour phase soldering) or conductive adhesive	no visible damage
4.5		visual inspection and dimension check	any applicable method using ×10 magnification	in accordance with specification
4.6.1		capacitance (measured 1000 hours after date of manufacture)	f = 1 kHz; measuring voltage 1 V _{rms} at 20 °C	within specified tolerance
4.6.2		tan δ	f = 1 kHz; measuring voltage 1 V _{rms} at 20 °C	in accordance with specification
4.6.3		insulation resistance	at U _R (DC) for 1 minute	in accordance with specification
4.6.4		voltage proof	$2.5 \times U_R$ for 1 minute	no breakdown or flashover
4.7.1		temperature coefficient	between minimum and maximum temperature	in accordance with specification
4.8		adhesion	a force of 5 N applied for 10 s to the line joining the terminations and in a plane parallel to the substrate	no visible damage
4.9		bond strength of plating on end face	mounted in accordance with IEC 60384 10, paragraph 4.4 conditions: bending 1 mm at a rate of 1 mm/s, radius jig 340 mm	no visible damage ∆C/C: ≤10%
4.10	Tb	resistance to soldering heat; jig clamps to the second component in the longitudinal line	260 \pm 5 °C for 10 \pm 0.5 s in a static solder bath	the terminations shall be well tinned after recovery $\Delta C/C$: ±10%
		resistance to leaching; jig clamps to the second component in the longitudinal line	260 \pm 5 °C for 30 \pm 1 s in a static solder bath	using visual enlargement of $\times 10$, dissolution of the terminations shall not exceed 10%

C Array: Class 1, NP0 50 V size 0612 (4 × 0603)

IEC 60384-10/ CECC 32 100 CLAUSE	IEC 60068-2 TEST METHOD	TEST	PROCEDURE	REQUIREMENTS
4.11	Та	solderability; jig clamps to the second component along the longitudinal line	zero hour test, and test after storage (20 to 24 months) in original packing in normal atmosphere; unmounted chips completely immersed for 2 ± 0.5 s in a solder bath at 235 \pm 5 °C	the terminations shall be well tinned
4.12	Na	rapid change of temperature	Preconditioning: between minimum and maximum temperature, 5 cycles	no visible damage after 24 hours recovery; $\Delta^{\circ}C/C: \le 15\%$
4.14	Са	damp heat	Preconditioning: 56 days at 40 °C; 90 to 95% RH; U _R applied	after 48 hours recovery: $\Delta^{\circ}C/C: \pm 15\%$ tan $\delta: 7\%$ R _{ins} : 1000 M Ω or R _i C _R ≥ 25 s, whichever is less
4.15		endurance	Preconditioning: (thermal treatment) $2 \times U_R$ at 125 °C for 1000 hours, recovery 48 ±4 hours at room temperature	after 48 hours recovery: Δ° C/C: ±20% tan δ : 7% R _{ins} : 2000 M Ω or R _i C _R ≥ 25 s, whichever is less

C Array: Class 1, NP0 50 V size 0612 (4 × 0603)

REVISION HISTORY

Revision	Date	Change Notification	Description
Rev.5	2001 May 30	-	- Converted to Phycomp brand
Rev.6	2003 Mar 04	-	- Updated company logo
Rev.7	2003 Jul 18	-	- Cover page revised